

Specification Proposal for NX8560LJ-BC/CC189

Custo	Customer: PHOTONICSystems								
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TITI	LE: 10Gb/s EA /DFB								
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NOTE:

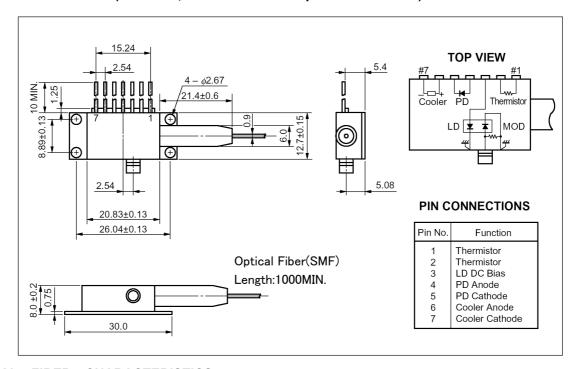
Please contact with responsible supplier person. If you require any modifications of this specification.

SALES ENGINEERING Gr.
SALES DIVISION
NEC COMPOUND SEMICONDOCUTOR DEVICES, LTD.

DISK NO.: GBB0494

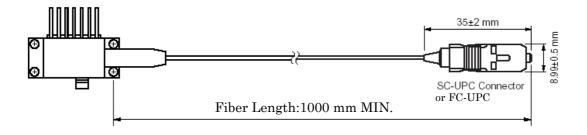


PACKAGE DIMENSIONS(UNIT:mm, unless otherwise specified +/-0.2mm)



OPTICAL FIBER CHARACTERISTICS

Parameter	Specification	Unit	
Mode Field Diameter	9.3±0.5	μm	
Cladding Diameter	125±1	μm	
Tight Buffer Diameter	900±100	μm	
Cut-off Wavelength	< 1 270	nm	
Attenuation 1 525 to 1 575 nm	< 0.3	dB/km	
Minimum Fiber Bending Radius	30	mm	
Fiber Length	1 000 MIN.	mm	
Flammability	UL1581 VW-1		





Ordering information:

•NX8560LJ-BC189 : with FC Connector

•NX8560LJ-CC189 : with SC Connector

ABSOLUTE MAXIMUM RATINGS:

Parameter	Symbol	Ratings	Unit
Optical Output Power from Fiber	Pf	10	mW
Forward Current of LD	I FLD	150	mA
Reverse Voltage of LD	VRLD	2.0	٧
Forward Voltage of Modulator	VFEA	1	٧
Reverse Voltage of Modulator	VREA	4	٧
Forward Current of PD	I FPD	1	mA
Reverse Voltage of PD	V _{RPD}	10	٧
Cooler Current	lc	1.5	Α
Cooler Voltage	Vc	2.5	٧
Operating Case Temperature	Tc	−20 to +70	°C
Storage Temperature	T _{stg}	-40 to +85	°C
Lead Soldering Temperature (10 sec.)	Tsld	260	°C



ELECTRO-OPTICAL CHARACTERISTICS

(TLD = 25 °C, Tc = 25 °C, BOL, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Laser Set Temperatrue	Tset	*1	20		35	°C
Operating Current	Іор	T _{LD} = T _{set}	50	60	80	mA
Modulation Center Voltage	Vcenter		-2.0		-0.5	V
Modulation Voltage	V _{mod}			2	2.7	V
Forward Voltage of LD	V _{FLD}	I _{FLD} = I _{op}			2.0	V
Threshold Current	Ith	T _{LD} = T _{set}		6	20	mA
Optical Output Power from Fiber	Pf	Under modulation *2	-3			dBm
Peak Emission Wavelength	λρ	I _{FLD} = I _{op} , V _{EA} = 0 V, T _{LD} = T _{set}	1530		1563	nm
Side Mode Suppression Ratio	SMSR	I _{FLD} = I _{op} , V _{EA} = 0 V	30			dB
Extinction Ratio	ER	Under modulation *2	8.2	10		dB
Rise Time	tr	20-80%, Under modulation *2			40	ps
Fall Time	tf	80-20%, Under modulation *2			40	ps
Optical Isolation	ls		23			dB
RF Return Loss	S ₁₁	I _{FLD} = I _{op} , V _{EA} =-1V 130 MHz to 5 GHz		-10	-8	dB
		I _{FLD} = I _{op} , V _{EA} =-1V 5 to 10 GHz		-8	- 5	

^{*1} NX8560LJ-CC: T_{set} is a certain point between 20°C and 35°C

*2 9.95328 Gb/s, PRBS 2^{23-1} , VEA = V_{center} \pm 1/2V_{mod}, I_{FLD}=I_{op}, T_{LD=}T_{SET}, NEC Test System

 $\ensuremath{V_{center}}\xspace$: a certain point between –0.5 V and –2.0 V

 V_{mod} : a certain point below 2.7 V

 I_{op} : a certain point between 50 mA and 80 mA

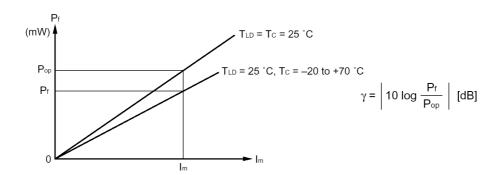


ELECTRO-OPTICAL CHARACTERISTICS

(Applicable to Monitor PD: $T_{LD} = 25$ °C, $T_{C} = -20$ to +70 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Monitor Current	lm	V _{RPD} = 5 V, I _{FLD} = I _{op} , V _{EA} = 0 V	30		1 100	μА
Dark Current	lσ	V _{RPD} = 5 V, V _{EA} = 0 V			10	nA
Terminal Capacitance	Ct	V _{RPD} = 5 V, f = 1 MHz			15	pF
Tracking Error	.γ *1	Im = const.			0.5	dB

*1
$$\gamma$$
 = $\left| 10 \log - \frac{P_{\rm f}}{P_{\rm op}} \right|$



ELECTRO-OPTICAL CHARACTERISTICS

(Applicable to Thermistor and TEC: T_{LD} = 25 °C, T_{C} = -20 to +70 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Thermistor Resistance	R	T _{LD} = 25 °C	9.5	10.0	10.5	kΩ
B Constant	В		3 350	3 450	3 550	K
Cooler Current	lc	ΔT = 50 °C			1.2	Α
Cooler Voltage	Vc	ΔT = 50 °C			2.4	V